

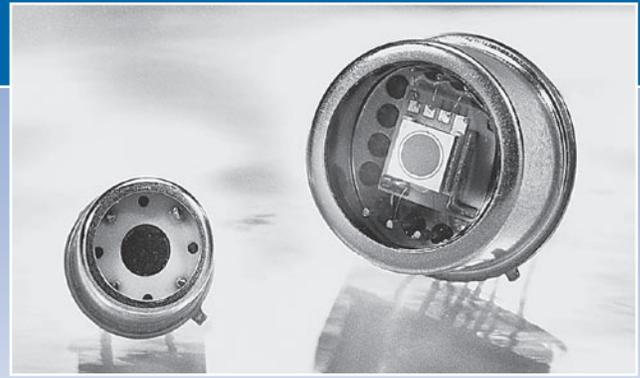
■ Dual Sandwich Detector Series

Two Color Photodiodes

Dual Sandwich Detectors or Two Color Detectors are mostly employed for remote temperature measurements. The temperature is measured by taking the ratio of radiation intensities of two adjacent wavelengths and comparing them with the standard black body radiation curves. The advantages of optical remote measurement have definitely made these devices the perfect match for this type of measurements. They are independent of emissivity and unaffected by contaminants in the field of view or moving targets. In addition, measurements of targets out of the direct line of sight and the ability to function from outside RF/EMI interference or vacuum areas are possible. They also have the advantages of overcoming obstructed target views, blockages from sight tubes, channels or screens, atmospheric smoke, steam, or dust, dirty windows as well as targets smaller than field of view and/or moving within the field of view. These detectors can also be used in applications where wide wavelength range of detection is needed.

OSI Optoelectronics offers three types of dual sandwich detectors. The Silicon-Silicon sandwich, in which one silicon photodiode is placed on top of the other, with the photons of shorter wavelengths absorbed in the top silicon and the photons of longer wavelengths penetrating deeper, absorbed by the bottom photodiode. For applications requiring a wider range of wavelength beyond 1.1 μm , an InGaAs photodiode replaces the bottom photodiode. The Silicon-InGaAs version is also available with a two stage thermo-electric cooler for more accurate measurements by stabilizing the temperature of the InGaAs detector.

All devices are designed for photovoltaic operation (no bias), however, they may be biased if needed, to the maximum reverse voltage specified. They are ideal for coupling to an operational amplifier in the current mode. For further details refer to the "Photodiode Characteristics" section of this catalog.



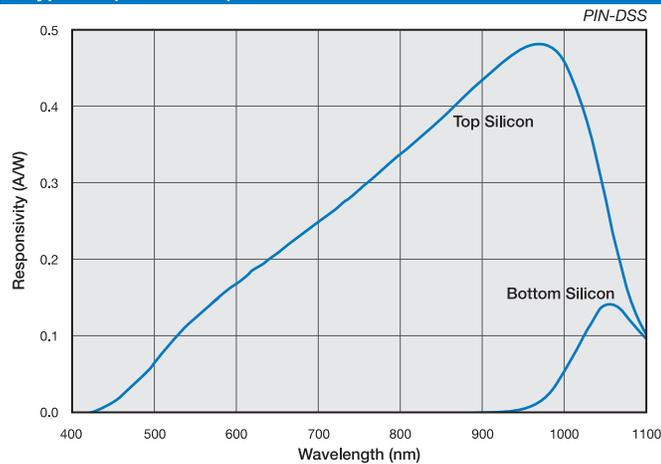
■ APPLICATIONS

- Flame Temperature sensing
- Spectrophotometer
- Dual-wavelength detection
- IR Thermometers for Heat Treating, induction heating, and other metal parts processing

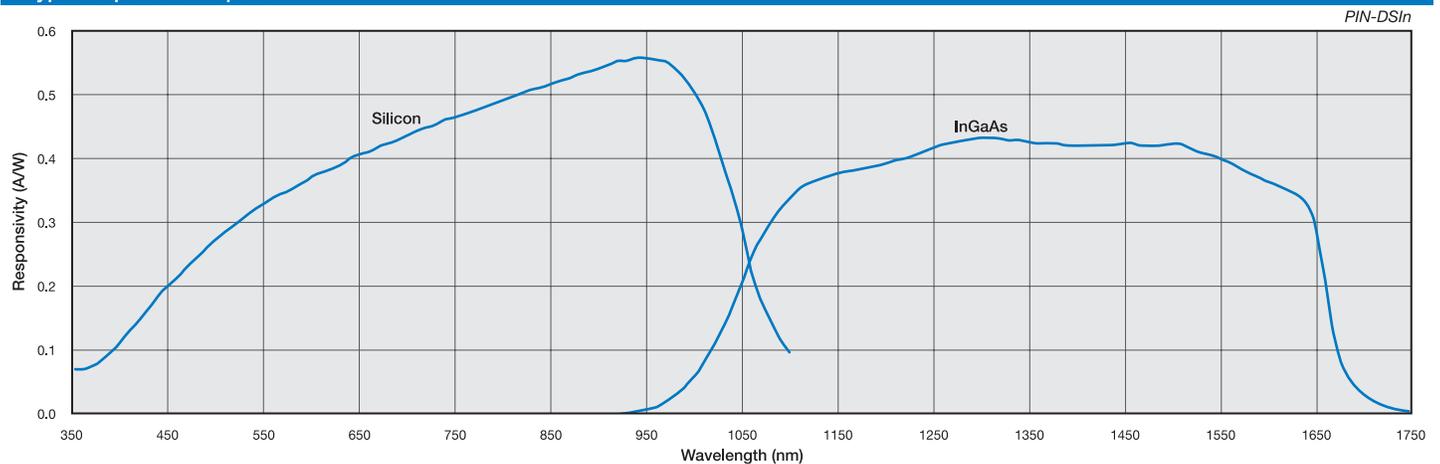
■ FEATURES

- Compact
- Hermetically Sealed
- Low Noise
- Wide Wavelength Range
- Remote Measurements
- w/ TEC

■ Typical Spectral Response



■ Typical Spectral Response



Dual Sandwich Detector Series

Typical Electro-Optical Specifications at $T_A=23^\circ\text{C}$

Model Number	Detector Element	Active Area	Spectral Range (nm)	Peak Wavelength	Responsivity	Capacitance	Shunt Resistance		NEP	D* @ peak	Reverse Voltage	Rise Time (μs)	Temp* Range ($^\circ\text{C}$)		Package Style ¶
		Dimension (mm)		nm	λ_p	0 V	-10 mV	0V, λ_p	0V, λ_p	V	0 V 50 Ω λ_p	Operating	Storage		
					A/W	pF	M Ω	(W/ $\sqrt{\text{Hz}}$)	($\text{cm}\sqrt{\text{Hz/W}}$)						
		typ.	typ.	typ.	min.	typ.	typ.	max.	typ.						
Non-Cooled															
PIN-DSS	Si (top)	2.54 ϕ	400-1100	950	0.45	70	50	500	1.3 e -14	1.7 e +13	5	10	-40 ~ +100	-55 ~ +125	17 / TO-5
	Si		950-1100	1060	0.12				4.8 e -14	4.7 e +12		150			
PIN-DSIn	Si (top)	2.54 ϕ	400-1100	950	0.55 §	450	150	1.9 e -14 §	1.2 e +13 §	5	4	-40 ~ +100	-55 ~ +125	24 / TO-8	
	InGaAs	1.50 ϕ	1000-1800	1300	0.60	300	1.0	2.1 e -13	8.4 e +11	2	4				
Two Stage Thermoelectrically Cooled ‡															
PIN-DSIn-TEC	Si (top)	2.54 ϕ	400-1100	950	0.55 §	450	150	1.9 e -14 §	1.2 e +13 §	5	4	-40 ~ +100	-55 ~ +125	24 / TO-8	
	InGaAs	1.5 ϕ	1000-1800	1300	0.60	300	1.0	2.1 e -13	8.4 e +11	2	4				

§ @ 870 nm

‡ Thermo-Electric Cooler and Thermistor Specifications are specified in the tables below.

¶ For mechanical drawings please refer to pages 58 thru 69.

* Non-Condensing temperature and Storage Range, Non-Condensing Environment.

Thermistor Specifications

PARAMETER	CONDITION	SPECIFICATION
Temperature Range	---	-100 $^\circ\text{C}$ to +100 $^\circ\text{C}$
Nominal Resistance	---	1.25 KW @ 25 $^\circ\text{C}$
Accuracy	-100 $^\circ\text{C}$ to -25 $^\circ\text{C}$	± 6.5 $^\circ\text{C}$
	-25 $^\circ\text{C}$ to +50 $^\circ\text{C}$	± 3.5 $^\circ\text{C}$
	@ 25 $^\circ\text{C}$	± 1.5 $^\circ\text{C}$
	+50 $^\circ\text{C}$ to +100 $^\circ\text{C}$	± 6.7 $^\circ\text{C}$

Two Stage Thermo-electric Cooler Specifications

PARAMETER	SYMBOL	CONDITION	SPECIFICATION
Maximum Achievable Temperature Difference	ΔT_{MAX} ($^\circ\text{C}$)	I = I_{MAX} QC = 0	Vacuum
		Dry N2	91
Maximum Amount Of Heat Absorbed At The Cold Face	Q_{MAX} (W)	I = I_{MAX} , $\Delta T = 0$	0.92
Input Current Resulting In Greatest ΔT_{MAX}	I_{MAX} (A)	---	1.4
Voltage At ΔT_{MAX}	V_{MAX} (V)	---	2.0